

EYP-RWE-0760-02010-1500-SOT12-0000

Revision 1.00

GAIN CHIPSAR coated Fabry-Perot Laser

General Product Information

Absolute Maximum Ratings



Product	Application
tunable 760 nm Fabry-Perot Laser	Spectroscopy
for use in an External Cavity Diode Laser (ECDL)	covering wavelengths
sealed SOT Housing	between 752 and 772 nnm
Monitor Diode	



Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T _S	°C	-40		85
Operational Temperature at Case	T _C	°C	-20		50
Forward Current	I _F	mA			200
Reverse Voltage	V_R	V			0
Output Power (extracavity)	P _{opt}	mW			100

Measurement Conditions / Comments				
Stress in excess of one of the Absolute Maximum				
Ratings can cause permanent damage to the device.				
Please note that a damaging optical power level may				
occur although the maximum current is not reached.				

Recommended Operational Conditions					
Symbol	Unit	min	typ	max	
T _C	°C	15		40	
I _F	mA			180	
P_{opt}	mW			80	
	Symbol T _C I _F	Symbol Unit T _C °C I _F mA	Symbol Unit min T _C °C 15 I _F mA	Symbol Unit min typ T _C °C 15 I _F mA	

Characteristics at 25° C at Begin Of Life

Measurement Conditions / Comments

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ _C	nm		760	
Tuning Range	$\Delta \lambda_{tun}$	nm	752		772
Output Power (extracavity)	P _{opt}	mW		80	
Cavity Length	L	μm		1500	
Reflectivity at Front Facet	R_{ff}			3·10 ⁻⁴	1.10-3
Polarization				TM	
Degree of Polarization	DOP	%		85	
Spatial Mode (transversal) TEM ₀₀					
Divergence parallel (FWHM)	$\Theta_{ }$	0		10	
Divergence perpendicular (FWHM)	Θ_{\perp}	0		28	
Beam diameter	d0x	μm		4	
Beam diameter	d0y	μm		1.5	

Tuning range and output power are estimated from
the gain profile of the laser. The actual achieved
wavelength and power are strongly influenced by the
external cavity. Therefore eagleyard Photonics will
give no guarantee on these parameters.
E field perpendicular to Pin 2 - Pin 3 - plane
Fundamental Mode
parallel to Pin 2 - Pin 3 plane (see p. 3)
perpendicular to Pin 2 - Pin 3 plane (see p. 3)
1/e2
1/e2

Measurement Conditions / Comments



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Monitor Diode					
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity ($U_{R MD} = 5 V$)	I _{mon} / P _{opt}	μA / mW	0.1		100

Measurement Conditions / Comments			
depends on the intracavity power of the ECDL setup			

Symbol	Unit	min	typ	max
d_{EP}	mm	3.50	3.65	3.70
R	mm			0.12
I _{PIN}	mm		14	
	d _{EP}	d _{EP} mm	d _{EP} mm 3.50	d _{EP} mm 3.50 3.65 R mm

Measurement Conditions / Comments
reference plane: top side of TO header
reference: center of outer diameter of header

		_
Packag	e Pi	nout

Package Dimensions

- 2 Photo Diode Anode

1 Laser Diode Anode Monitor Diode Cathode, Case

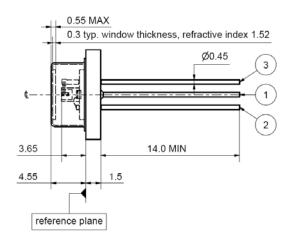
3 Laser Diode Cathode

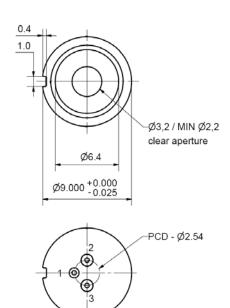


M-type



Package Drawings





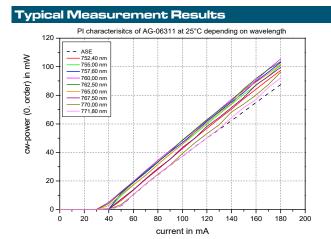


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Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The RWE diode type is known to be sensitive against thermal stress. It should not be operated without appropriate optical feedback from an external cavity. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.

Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.



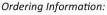














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